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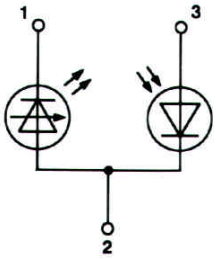
RLT6615G TECHNICAL DATA

High Power Visible Wavelength Laserdiode

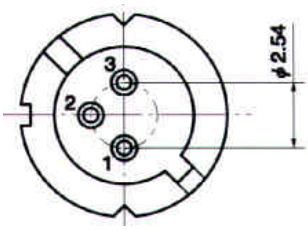
Structure: **AlGaInP, index guided**
Lasing wavelength: **660 nm typ.**
Max. optical power: **15 mW**
Package: **9 mm**

NOTE!
LASERDIODE
MUST BE COOLED!

PIN CONNECTION:



1) Laser diode cathode
2) Laser diode anode and photodiode cathode
3) Photodiode anode



Absolute Maximum Ratings (Tc=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	P_o	15	mW
LD Reverse Voltage	$V_{R(LD)}$	2	V
PD Reverse Voltage	$V_{R(PD)}$	30	V
Operation Case Temperature	T_C	-10 .. +50	°C
Storage Temperature	T_{STG}	-40 .. +85	°C

Optical-Electrical Characteristics (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Threshold Current	I_{th}		25	40	60	mA
Operation Current	I_{op}	P_o = 15 mW		50	70	mA
Operating Voltage	V_{op}	P_o = 15 mW		2.5	2.6	V
Lasing Wavelength	I_p	P_o = 15 mW		660	665	nm
Beam Divergence	$\theta_{//}$	P_o = 15 mW	6	9	16	°
Beam Divergence	$\theta_{\perp}$	P_o = 15 mW		30		°
Monitor Current	I_m	P_o = 15 mW		100		µA
Astigmatism	A_s	P_o = 15 mW		11		µm